### SN54LS620, SN54LS621, SN74LS620, SN74LS621, SN74LS623 OCTAL BUS TRANSCEIVERS SDLS185 D2537, AUGUST 1979-REVISED MARCH 1988

- Bidirectional Bus Transceivers in High-Density 20-Pin Packages
- Local Bus-Latch Capability
- Hysteresis at Bus Inputs Improves
  Noise Margins
- Choice of True or Inverting Logic
- Choice of 3-State or Open-Collector
  Outputs

DEVICE	OUTPUT	LOGIC
′LS620	3-State	Inverting
'L\$621	Open-Collector	True
'LS623	3-State	True

### description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing.

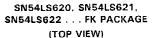
These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic levels at the enable inputs  $\{\overline{G}BA$  and  $GAB\}$ .

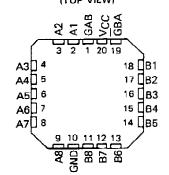
The enable inputs can be used to disable the device so that the buses are effectively isolated.

The dual-enable configuration gives the 'LS620, 'LS621, and 'LS623 the capability to store data by simultaneous enabling of  $\overline{G}BA$  and GAB. Each output reinforces its input in this transceiver configuration. Thus, when both control inputs are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 in all) will remain at their last states. The 8-bit codes appearing on the two sets of buses will be identical for the 'LS621 and 'LS623 devices or complementary for the 'LS620.

SN54LS620, SN54LS621,
SN54LS622 J PACKAGE
SN74LS620, SN74LS621,
SN74LS623 DW OR N PACKAGE
(TOP VIEW)

•			,
GAB A1 A2 A3 A4 A5 A6 A7 A8 GND	1 2 3 4 5 6 7 8 9 10	20 19 18 17 16 15 14 13 12 11	VCC GBA B1 B2 B3 B4 B5 B6 B7 B8





#### FUNCTION TABLE

ENABLE	INPUTS	OPERA	ATION
ĞВА	GAB	LS620	'LS621, 'LS623
L	L	B data to A bus	Bidata to A bus
н	н	A data to B bus	A data to B bus
н	L	Isolation	Isolation
		B data to A bus,	B data to A bus,
L	H	A data to B bus	A data to B bus

H = high level, L = low level

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub> (see Note 1)	7V
Input voltage	7 V
Off-state output voltage	5.5 V
Operating free-air temperature range: SN54LS'	to 125°C
SN74LS'	C to 70°C
Storage temperature range	to 150°C

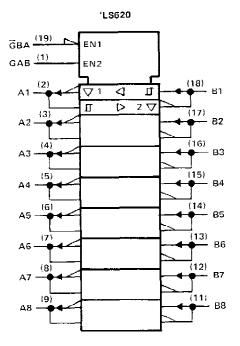
NOTE 1: Voltage values are with respect to network ground terminal.

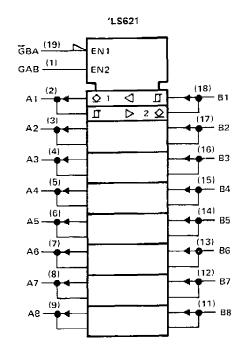
PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas instruments standard warranty. Production processing does not necessarily include testing of all parameters.



# SN54LS620, SN54LS621, SN74LS620, SN74LS621, SN74LS623 Octal bus transceivers

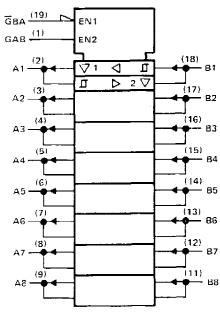
logic symbols<sup>†</sup>





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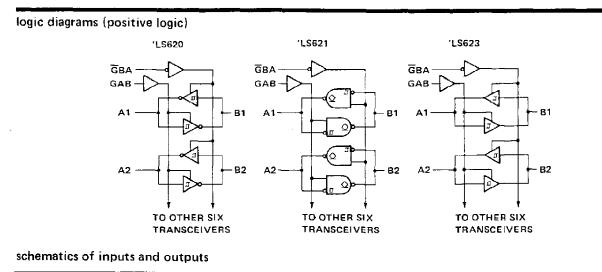


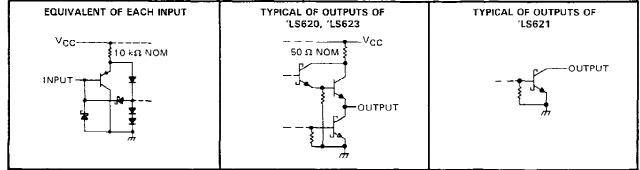


<sup>1</sup> These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for DW, J, and N packages.



## SN54LS620, SN54LS621, SN74LS620, SN74LS621, SN74LS623 Octal bus transceivers





\*. .



## SN54LS620, SN74LS620, SN74LS623 OCTAL BUS TRANSCEIVERS WITH 3 STATE OUTPUTS

#### recommended operating conditions

PARAMETER	SI	20	SI SI	UNIT			
	MIN	NOM	MAX	MIN	NOM	MAX	L
Supply voltage, V <sub>CC</sub> (see Note 1)	4.5	5	5.5	4.75	5	5.25	<u>v</u>
High-level output current, IOH			-12			-15	mА
Low-level output current, IOL			12			24	mA_
Operating free-air temperature, TA	55		125	0		70	°C

NOTE 1: Voltage values are with respect to network ground terminal.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER			DITIONS	sr	N54LS6	20		20 23	UNIT	
					MIN	TΥΡ‡	MAX	MIN	TYP‡	MAX	
 УIН	High-level input voltage		-		2			2			_ V
VIL	Low-level input voltage						0.5			0.6	V
Vik	Input clamp voltage		V <sub>CC</sub> = MIN,	l <sub>l</sub> ≠ –18 mA			-1.5			-1.5	<u>v</u>
	Hysteresis (VT+ - VT_) A or	r B input	VCC = MIN		0.1	0.4		0.2	0.4		V _
			V <sub>CC</sub> ≈ MIN,	<sup>I</sup> OH = -3 mA	2.4	3.4		2.4	3.4		v
∨он			ut voltage VIH = 2 V, VIL = VIL max	I <sub>OH</sub> = MAX	2			2			
			Vcc = MIN,	l <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	
Vo∟	Low-level output voltage		V <sub>IH</sub> = 2 V, V <sub>II</sub> = V <sub>II</sub> max	IOL = 24 mA					0.35	0.5	
<sup>I</sup> OZH	Off-state output current, high-level voltage applied		V <sub>CC</sub> = MAX, V <sub>O</sub> = 2,7 V	G at 2 V,			20			20	μА
IDZL	Off-state output current.		V <sub>CC</sub> = MAX, V <sub>O</sub> = 0.4 V	Gat2∨,			-400			400	μА
	Input current at	AorB		VI = 5.5 V			0.1			0.1	mA
4	maximum input voltage	GBA or GAB	VCC = MAX,	V1 = 7 V			0.1			0.1	
ЧΗ	High-level input current	<u> </u>	V <sub>CC</sub> = MAX,	V1 = 2.7 V			20			20	Αų
ήL	Low-level input current		V <sub>CC</sub> = MAX,	V <sub>I</sub> = 0.4 V			-0.4			-0.4	mA
los	Short-circuit output current §	ş	VCC = MAX		-40		-225	-40		-225	MA
		Outputs high				48	70		48	70	1
lcc	Total supply current	Outputs low	V <sub>CC</sub> = MAX,	Outputs open		62	90		62	90	mA
		Outputs at Hi-Z				64	95		64	95	

<sup>†</sup> For conditions shown as MIN or MAX use the appropriate value specified under recommended operating conditions.

 $\ddagger$ All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25<sup>o</sup>C.

Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

## switching characteristics at VCC = 5 V, TA = $25^{\circ}$ C

PARAMETER		PARAMETER FROM TO TEST CO		TEST CONDITIONS	IONS (LS620			s	UNIT		
		(INPUT)	(OUTPUT)		MIN	TYP	MAX	MIN	ТҮР	MAX	]
	Propagation delay time,	A	В			6	10		8	15	ns
<sup>t</sup> PLH	low-to-high-level output	8	A	0 - 46 - 5		6	10		8	15	
	Propagation delay time,	A	В	С <sub>L</sub> = 45 рF,		8	15		11	15	ns
t₽HL	high-to-low-level output	В	A	<b>B 00</b> 0		8	15		11	15	113
		Ğва	A	$R_L = 667 \Omega$ ,		31	40		31	40	-
†PZL	Output enable time to low level	GA8	В			31	40		31	40	ns
		GBA	A	See Note 2		23	40		26	40	
<sup>t</sup> PZH	Output enable time to high level	GAB	В			23	40		26	40	ns
		GBA	A			15	25	[ .	15	25	
<sup>t</sup> PLZ	Output disable time from low level	GAB	В	CL=5pF,		15	25		15	25	ns
		ĞВА	A	$R_{L} = 667 \Omega,$		15	25		15	25	
¹₽HZ	Output disable time from high level	GAB	В	See Note 2		15	25		15	25	i ns

 $t_{PLH}$  = Propagation delay time, low-to-high-level output

 $\label{eq:theta} \begin{array}{l} t_{PHL} = \text{Propagation delay time, low-to-low-level output} \\ t_{PHL} = \text{Propagation delay time, high-to-low-level output} \\ t_{PZH} = \text{Output enable time to high level} \end{array}$ 

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

t<sub>PZL</sub> = Output enable time to low level t<sub>PHZ</sub> = Output disable time from high level

tPLZ = Output disable time from low level



# SN54LS621, SN74LS621 OCTAL BUS TRANSCEIVERS WITH OPEN-COLLECTOR OUTPUTS

recommended operating conditions

PARAMETER	s	N54LS	621	s	SN74LS621			
	MIN	NOM	MAX	MIN	NOM	MAX	1	
Supply voltage, VCC (see Note 1)	4.5	5	5.5	4.75	5	5.25	V	
High-level output voltage, VOH	· ·		5.5			5.5	V	
Low-level output current, IOL			12			24	mA	
Operating free-air temperature, TA	-55		125	0		70	°C	

NOTE 1: Voltage values are with respect to network ground terminal.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CON	TEST CONDITIONS <sup>†</sup>		SN54LS621			SN74LS621			
			TYP‡			MAX	MIN	ТҮР≑	MAX	}		
VIН	High-level input voltage				2			2			V	
VIL	Low-level input voltage						0.5	1		0.6	V	
Vik	input clamp voltage		VCC = MIN,	I <sub>I</sub> = -18 mA	1			1		-1.5	V	
	Hysteresis (V <sub>T+</sub> - V <sub>T</sub> _) A	or Binput	VCC = MIN		0.1	0.4		0.2	0.4		V	
юн	High-level output current		V <sub>CC</sub> = MIN, V <sub>IL</sub> = V <sub>IL</sub> max,				100			100	μА	
Vol	Low-level output voitage		V <sub>CC</sub> = MIN, V <sub>IH</sub> = 2 V,	I <sub>OL</sub> = 12 mA		0.25	0.4		0,25	0.4	v	
	· •			IOL = 24 mA					0.35	0.5		
	Input current at	A or B		5.5 V			0.1			0.1		
1	maximum input voltage	GAB or GBA	$V_{CC} = MAX,$	V1 = 7 V			0.1			0.1	mA	
Чн	High-level input current		V <sub>CC</sub> = MAX,	Vi = 2.7 V			20			20	μA	
ΊL	Low-level input current		VCC = MAX,	V <sub>1</sub> = 0.4 V			-0,4	<u> </u>		-0.4	mA	
lcc	Total supply current	Outputs high	VCC = MAX,	Outputs open		48	70		48	70	mA	
	Outputs low		·CC ··································	Outpots open		62	90		62	90		

<sup>†</sup>For conditions shown as MIN or MAX use the appropriate value specified under recommended operating conditions. ‡All typical values are at  $V_{CC} = 5 V$ ,  $T_A = 25^{\circ}C$ .

# switching characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = $25 \,^{\circ}$ C

	DADAMETER	FROM	то	TEST CONDITIONS		'LS621		UNIT	
	PARAMETER	(INPUT)	(INPUT) (OUTPUT)		MIN	TYP	MAX	UNIT	
•	Propagation delay time,	A	В			17	25		
<sup>t</sup> PLH	low-to-high-level output	В	A			17	25	.5 <sup>ns</sup>	
	Propagation delay time,	A	В	$C_{L} = 45 \text{ pF},$		16	25	ńs	
<sup>1</sup> PHL	high-to-low-level output	В	A			16	25		
	Output disable time	Ğва	A	$- R_{L} = 667 \Omega,$		23	40		
<sup>t</sup> PLH	from low level	GAB	8	See Note 2		25	40	ns	
	Output enable time	GBA	A	-		34	50		
<sup>t</sup> PHL	from high level	GAB	В			37	50	- 15	

 $t_{\text{PLH}} = Propagation delay time, low-to-high-level output$ 

tpHL = Propagation delay time, high-to-low-level output

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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